



## 1N5817 THRU 1N5819

### SCHOTTKY BARRIER RECTIFIER

TECHNICAL  
SPECIFICATION

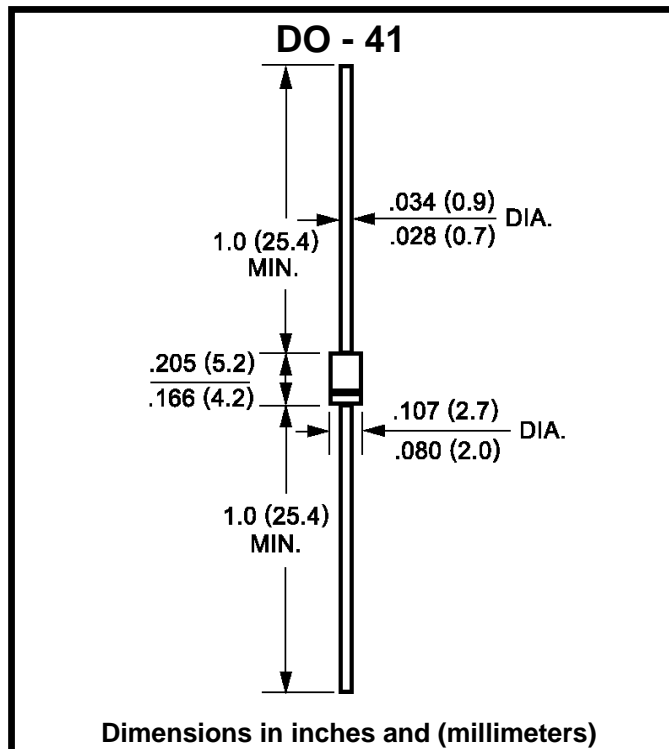
**VOLTAGE: 20 TO 40V CURRENT: 1.0A**

#### FEATURES

- Epitaxial construction for chip
- High current capability
- Low forward voltage drop
- Low power loss, high efficiency
- High surge capability
- High temperature soldering guaranteed:  
250°C/10sec/0.375"(9.5mm) lead length  
at 5 lbs tension

#### MECHANICAL DATA

- Terminal: Plated axial leads solderable per  
MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O  
recognized flame retardant epoxy
- Polarity: Color band denotes cathode
- Mounting position: Any



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	1N5817	1N5818	1N5819	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	20	30	40	V
Maximum RMS Voltage	$V_{RMS}$	14	21	28	V
Maximum DC Blocking Voltage	$V_{DC}$	20	30	40	V
Maximum Average Forward Rectified Current (9.5mm lead length, at $T_L=90^\circ\text{C}$ )	$I_{F(AV)}$	1.0			A
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	$I_{FSM}$	25			A
Maximum Forward Voltage (at 1.0A DC)	$V_F$	0.45	0.55	0.6	V
Maximum DC Reverse Current (at rated DC blocking voltage)	$I_R$	1.0 10.0			mA mA
Typical Junction Capacitance (Note 1)	$C_J$	110			pF
Typical Thermal Resistance (Note 2)	$R_{\theta(ja)}$	50			°C/W
Storage and Operation Junction Temperature	$T_{STG}, T_J$	-65 to +125			°C

Note:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0V<sub>dc</sub>

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, vertical P.C. board mounted